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Ultrasonic Attenuation of a Void-Containing Medium for Very Long Wavelengths

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INTRODUCTION

In ultrasonic nondestructive evaluation (NDE), the nondestructive interrogation energy is transmitted by propagating stress waves. The parameters which govern the mechanical behavior of materials also affect their stress wave propagation characteristics.

A useful parameter in describing stress wave propagation in a medium is attenuation. Attenuation refers to the energy loss associated with the decrease in the stress wave amplitude due to both scattering and absorption. It has been observed that attenuation can be correlated with the tensile strength of flawed glass fiber composites [1] and the residual strength of impact-damaged graphite fiber composites [2]. It has also been observed that attenuation of as-fabricated graphite fiber composites can be correlated with the compression fatigue life [3] and flexural fatigue life [4]. In rock structures, attenuation of seismic waves is a major topic in exploration seismology [5].

The two major sources of ultrasonic attenuation are absorption due to viscoelastic effects of the medium and scattering from inhomogeneities in the ultrasonic beam path.

This study considers only attenuation due to scattering by voids in the medium. In the theoretical analysis, the geometries of the voids considered are spherical and ellipsoidal. The medium is assumed to be isotropic and the incident ultrasonic beam is assumed to be a plane longitudinal wave of wavelength much larger than the largest dimension of the void.
THEORETICAL ANALYSIS

An incident ultrasonic wave is scattered into various directions by voids present in the medium. In this analysis, the energy carried in the scattered wave is assumed to be entirely lost, thus contributing to ultrasonic attenuation.

It is also assumed that no interaction occurs between neighboring voids in the medium containing many randomly distributed voids. Large spacings between voids are not required in order to neglect void interactions [6,7]. It has been observed that longitudinal wave speed and attenuation developed using the void non-interaction assumption are valid up to 20% of void volume fraction [8]. Thus, scattering from an individual void can be treated independently for most void volume fractions of engineering interest. So, the combined effect of multiple voids is simply the arithmetic addition of their individual contributions.

An obstacle which scatters an incident ultrasonic wave can be described by its scattering cross section $\gamma$ [9]. The scattering cross section of a scatterer is defined as the ratio of the total power scattered to the incident power flux. The scattering cross section has dimensions corresponding to area.

The scattering cross sections for a spherical void and an ellipsoidal void will be discussed below. Then an analysis is developed for evaluating the ultrasonic through-thickness attenuation based on scattering. The medium is assumed to be isotropic. The incident wave is assumed to be a plane longitudinal wave have a wavelength much larger than the largest dimension of the void.

Scattering from a Spherical Void

The exact solution for the scattering cross section $\gamma_s$ having a spherical void of volume $V$ for an incident longitudinal wave with wave number $k_p$ is [9]

$$\gamma_s = V^2 k_p^4 g_c$$

(1)

where

$$g_c = \frac{1}{4\pi} \left[ \frac{4}{3} + 40 \frac{2 + 3c^5}{(4 - 9c^2)^2} - \frac{3}{2} c^2 + \frac{2}{3} c^3 + \frac{9}{16} c^4 \right]$$

(2)

and where

$$c = \frac{c_s}{c_p} = \frac{k_s}{k_p}.$$
The wave speed of the incident longitudinal wave is $c_p$, and $c_s$ and $k_s$ are the wave speed and wave number of the corresponding shear wave, respectively, having the same frequency as the incident longitudinal wave.

Eqn. (1) gives the exact scattering cross section of a spherical void for an incident longitudinal wave. From eqn. (1), it is observed that the scattering cross section is proportional to the square of the volume of the void and proportional to the fourth power of the incident wave number. Because the wave number $k_p$ is related to the wavelength $\lambda_p$ as

$$k_p = \frac{2\pi}{\lambda_p},$$

the scattering cross section is inversely proportional to the fourth power of the incident wavelength.

The scattering cross section $\gamma_s$ in eqn. (1) also depends on the parameter $c$ which is the ratio of the shear to longitudinal wave numbers through the term $g_c$ defined in eqn. (2). Fig. 1 shows the scattering cross section of a spherical void for incident longitudinal waves versus $c$, based on eqns. (1), (2) and (3).

Scattering from an Ellipsoidal Void

No exact solution exists for the scattering cross section of an ellipsoidal void. An approximate solution will be derived below for the restrictions to be enumerated.

A schematic illustrating the scattering of ultrasonic wave by an ellipsoidal void is shown in Fig. 2. The center of the ellipsoidal void coincides with the origin of the $x,y,z$ cartesian coordinate system. The ellipsoid can be described by

$$\frac{x^2}{a_1^2} + \frac{y^2}{a_2^2} + \frac{z^2}{a_3^2} = 1,$$

where the principal dimensions of the ellipsoidal void are $2a_1$, $2a_2$ and $2a_3$ in the $x$, $y$ and $z$ directions, respectively. A plane ultrasonic longitudinal wave propagating in the $z$ direction impinges upon the ellipsoidal void. The incident wave is scattered by the void into all directions described by the polar angles $\theta$ and $\phi$ as shown in Fig. 2. The medium is assumed to be isotropic.

The scattering of ultrasonic waves by an ellipsoidal flaw has been considered using the so-called Born approximation technique [10,11]. The Born approximation represents the first iteration on the integral equation formulation of the scattering problem [10]. The physical consequence of the use of the Born approximation in the
The problem considered here is that the true displacement and strain fields inside the voids are replaced by the respective fields in the incident wave. When the Born approximation is applied to the scattering of an incident plane longitudinal wave having wave number $k_p$ by a spherical void of radius $a_o$, good agreement is obtained with the exact solution given in eqn. (1), in backscattering for wavelengths such that

$$k_p a_o < 1.$$  \hspace{1cm} (6)

That is, for scattered waves that propagate back towards the incident wave and which satisfy eqn. (6) \cite{11}.

The differential scattering cross section $\frac{d\gamma_e}{d\Omega}$ of an ellipsoidal void for an incident longitudinal wave based on the Born approximation is* \cite{11}

$$\frac{d\gamma_e}{d\Omega} = \frac{k_p^4}{(4\pi)^2} \left( -\cos \theta + \frac{\lambda + 2\mu \cos^2 \theta}{\lambda + 2\mu} \right)^2 S_{pp}^2$$

$$+ \frac{k k_s^3}{(4\pi)^2} \left( -\frac{k_p \sin 2\theta}{k_s} + \sin \theta \right) S_{ps}^2$$

(7)

where $\gamma_e$ is the scattering cross section of an ellipsoidal void for an incident longitudinal wave; $d\Omega$ is the differential solid angle which is defined by $\sin \theta \, d\theta \, d\phi$ with reference to $\theta$ and $\phi$ as shown in Fig. 2 \cite{12}; $\lambda$ and $\mu$ are the Lamé constants of the parent material; and $S_{pp}$ and $S_{ps}$ are the shape factors of the differential scattering cross section for incident longitudinal wave scattering into longitudinal and shear waves, respectively. The shape factors are \cite{11}

$$S_{pp} = \frac{4\pi a_1 a_2 a_3 (\sin \Delta K_{pp} - \Delta K_{pp} \cos \Delta K_{pp})}{(\Delta K_{pp})^3}$$

$$S_{ps} = \frac{4\pi a_1 a_2 a_3 (\sin \Delta K_{ps} - \Delta K_{ps} \cos \Delta K_{ps})}{(\Delta K_{ps})^3}$$

(8)

* Note that the term $4\pi^2$ is missing from eqn. (2.12) in \cite{11}.

-4-
where

\[ \Delta K_{pp} = k_p \left[ a_1^2 \sin^2 \theta \cos^2 \phi + a_2^2 \sin^2 \theta \sin^2 \phi + a_3^2 (1 - \cos \theta)^2 \right]^{1/2} \]

\[ \Delta K_{ps} = \left[ k_s a_1^2 \sin^2 \theta \cos^2 \phi + k_s a_2^2 \sin^2 \theta \sin^2 \phi + a_3^2 (k_p - k_s \cos \theta)^2 \right]^{1/2} \]

The scattering cross section \( \gamma_e \) of the ellipsoidal void can be obtained by integrating eqn. (7) over a closed spherical surface centered at the flaw as

\[ \gamma_e = \int_{\text{Surface}} \int_{\text{Enclosing Ellipsoid}} \frac{2\pi}{d\Omega} \sin \theta \, d\theta \, d\phi \] (10)

In order to examine the optimal utility of the Born approximation as used in [10,11], a further assumption is introduced by restricting this analysis to the very long wavelength regime such that

\[ k_p a_i << 1 \] (11)

where \( a_i \) is the largest dimension of the ellipsoidal void. Eqn. (11) represents the regime in which the Born approximation is at its best. From eqn. (9), it can be observed that \( \Delta K_{pp} \) and \( \Delta K_{ps} \) are of the order of \( k_p a_i \). Thus, the very long wavelength assumption in eqn. (11) requires \( \Delta K_{pp} \) and \( \Delta K_{ps} \) to be much less than unity. Then, the sine and cosine functions in eqn. (8) may be expanded into their respective Taylor series where only the first three terms will be retained.

After the Taylor series expansions are applied to eqns. (8), the result is substituted into eqn. (7), keeping only terms up to \( \Delta K_{pp}^2 \) and \( \Delta K_{ps}^2 \) which are evaluated using eqn. (9). Then, the resulting expression for \( \frac{d\gamma_e}{d\Omega} \) is substituted into eqn. (10) and the indicated integrations are performed to give the scattering cross section of an ellipsoidal void \( \gamma_e \) as

\[ \gamma_e = \nu^2 k_p^4 \left( g_{pp} \bar{s}_{pp} + g_{ps} \bar{s}_{ps} \right) \] (12)

where \( \nu \) is the volume of the ellipsoidal void given by
\[ V = \frac{4}{3} \pi a_1 a_2 a_3 \quad (13) \]

and

\[ g_{pp} = \frac{1}{15 \pi} \frac{(5c^4 - 10c^2 + 8)}{c^4} \quad (14) \]

\[ g_{ps} = \frac{1}{30 \pi} c(5c^2 + 4) . \]

The corresponding shape factors for the scattering cross section are

\[
\bar{S}_{pp} = 1 - \frac{k^2 a_2^2}{70} \left[ \frac{(21c^4 - 56c^2 + 48) \eta + 8(21c^4 - 28c^2 + 16)}{(5c^4 - 10c^2 + 8)} \right] \quad (15)
\]

\[
\bar{S}_{ps} = 1 - \frac{k^2 a_3^2}{35} \left[ \frac{2(7c^4 + 4c^2) \eta + (7c^4 - 9c^2 + 28)}{(5c^2 + 4)} \right]
\]

where

\[ \eta = \frac{a_1^2}{a_2^2} + \frac{a_2^2}{a_3^2} \quad (16) \]

Eqn. (12) gives the scattering cross section of an ellipsoidal void for an incident longitudinal wave with the very long wavelength assumption defined in eqn. (11), and based on the Born approximation.

The scattering cross section of an ellipsoidal void given in eqn. (12) is similar to that of a spherical void given in eqn. (1) because both scattering cross sections are proportional to the square of the volume of the void and proportional to the fourth power of the incident wave number. However, the shape of the void does not affect the scattering cross section of a spherical void beyond the contribution of its volume, whereas the void shape does affect the scattering cross section of an ellipsoidal void through the \( \bar{S}_{pp} \) and \( \bar{S}_{ps} \) shape factors.

It can be observed from eqns. (12) through (16) that the scattering cross section of an ellipsoidal void is the same if the dimensions \( a_1 \) and \( a_2 \) are interchanged. This is as expected because
interchanging $a_1$ and $a_2$ is equivalent to rotating the void about the z-axis, which on physical grounds should not affect the scattered power of a plane wave propagating in the z direction.

Additional observations on the effect of the shape of the void can be made by considering voids of the same volume $V$ and the same dimension $a_3$ for an incident wave at a fixed wave number $k_p$. Then, the only effect of the shape of the void on the scattering cross section is through the term $\eta$ defined in eqn. (16). For a void with $a_1$ equal to $a_2$; that is, a void that presents a circular cross-sectional area orthogonal to the incident wave, a specific value of $\eta$ is obtained from eqn. (16) and the corresponding $\gamma_e$ is obtained from eqn. (12) via the $\mathcal{S}_{pp}$ and $\mathcal{S}_{ps}$ terms defined in eqn. (15). For a void such that $a_1$ is much larger than $a_2$; that is, a void that presents an elongated elliptical cross-sectional area orthogonal to the incident wave, a larger value of $\eta$ and thus smaller values of $\mathcal{S}_{pp}$ and $\mathcal{S}_{ps}$ and correspondingly smaller $\gamma_e$ are obtained. Although the two voids have the same cross-sectional area ($\pi a_1 a_2$) orthogonal to the incident wave, the elongated void has a smaller scattering cross section. This is consistent with the expectation that an elongated void will provide less attenuation than that of a less elongated void.

The very long wavelength assumption in eqn. (11) results in the second terms in both $\mathcal{S}_{pp}$ and $\mathcal{S}_{ps}$ in eqn. (15) being much less than the first terms, unity. In fact, when $\gamma_e$ is evaluated from eqns. (12) through (16) for a range of $\eta$ from zero to 1,000,000, for $k_p a_3$ that satisfies eqn. (11) and for $c$ equal to 1.5, $\gamma_e$ is found to vary only by a maximum of 0.4%.

Thus, for an incident longitudinal wave having a wavelength that is very long compared with the largest dimension of the void as stated in eqn. (11), the exact shape of the void has little effect on the scattered power or the scattering cross section, which depends primarily on the volume of the void. In this case, the scattering cross section of a spherical void as given in eqn. (1) having the same volume as the arbitrarily shaped void can be used.

One further observation should be made regarding the accuracy of the Born approximation. The scattering cross section of an ellipsoidal void as given in eqn. (12) and obtained using the Born approximation can be used to compute the scattering cross section of a spherical void by letting $a_1$, $a_2$ and $a_3$ all be equal to $a_0$, the radius of a spherical void. Fig. 3 shows the ratio of the scattering cross section of a spherical void using the Born approximation in eqn. (12) to that of a spherical void using the exact solution in eqn. (1) versus $c$ for two values of $k_p a_0$. The Born approximation solution is observed to be insensitive to changes in $k_p a_0$ for very long wavelengths satisfying eqn. (11). From Fig. 3, the approximate solution obtained using the Born approximation is found to be at most 56% of that of the exact solution and this occurs at a value of $k_p a_0$ of zero and a value of $c$ of approximately 1.7. Thus, the accuracy of
the Born approximation for evaluating scattering cross sections is marginal, even for very long wavelengths. Nevertheless, the observation, based on the Born approximation, regarding the negligible effect of the exact shape of the void on the scattering cross section for very long wavelengths is expected to remain valid.

Ultrasonic Through-Thickness Attenuation due to Scattering by Voids

Ultrasonic attenuation can be measured experimentally by the through-thickness technique as illustrated schematically in Fig. 4. The ultrasonic through-thickness attenuation will be derived in terms of the scattering cross section of the voids and the void volume fraction of the specimen.

As shown in Fig. 4, an input ultrasonic transducer is assumed to apply a uniform pressure of amplitude $p_0$ that is sinusoidal in time on the surface of a specimen. It is further assumed that the planar area of the ultrasonic beam propagates through the specimen of thickness $l$ without alternation. (Such an assumption is obviously an oversimplification of the actual situation as a review of [13] will clearly indicate. Nevertheless, this model is adequate for the input-output relationship to be derived.) Portions of the input ultrasonic energy are scattered by the randomly distributed voids, numbering $n$ in the ultrasonic beam path. The output transmitted pressure is measured by a receiving ultrasonic transducer mounted on the opposite face of the specimen.

The output pressure is $p_e = p_0 e^{-\alpha l}$ where $\alpha$ is the attenuation which is a function of frequency. It is assumed that energy carried in the scattered waves is lost and that it represents the only energy dissipating mechanism considered here.

The intensity $I$ of a plane longitudinal travelling wave can be related to the pressure $p$ as [12]

$$I = \frac{p^2}{\rho c_p} \quad (17)$$

where $\rho$ is the mass density of the material and $c_p$ is the longitudinal wave speed. Thus, the incident ultrasonic intensity $I_0$ or power flux in Fig. 4 is

$$I_0 = \frac{p_0^2}{\rho c_p} \quad (18)$$

In accordance with the definition of the scattering cross section $\gamma$ [9], the power lost due to scattering from a single void is $\gamma I_0$. Assuming no interaction between voids, the total power lost due to scattering $\gamma$ Scattered by $n$ voids is
\[ P_{\text{Scattered}} = I_o \sum_{i=1}^{n} \gamma_i \]  

(19)

where \( n \) is the total number of voids in the ultrasonic beam and where the \( i \)-th void has scattering cross section \( \gamma_i \).

Substituting eqn. (18) into eqn. (19) gives

\[ P_{\text{Scattered}} = \frac{P_o^2}{\rho c_p} \sum_{i=1}^{n} \gamma_i . \]  

(20)

Using the planar area \( A \) of the ultrasonic beam, the input ultrasonic power can be obtained from eqn. (18) as

\[ P_{\text{In}} = \frac{P_o^2}{\rho c_p} A . \]  

(21)

Similarly, the output ultrasonic power can be obtained as

\[ P_{\text{Out}} = \frac{(p_e^{-\alpha l})^2}{\rho c_p} A . \]  

(22)

So, the equation for energy balance is

\[ P_{\text{In}} - P_{\text{Scattered}} = P_{\text{Out}} . \]  

(23)

Substituting eqns. (20) to (22) into eqn. (23) gives

\[ \frac{P_o^2}{\rho c_p} A - \frac{P_o^2}{\rho c_p} \sum_{i=1}^{n} \gamma_i = \frac{(p_e^{-\alpha l})^2}{\rho c_p} A \]  

(24)

which simplifies to
Eqn. (25) can be solved for the attenuation as
\[ \alpha = -\frac{1}{2l} \ln \left( 1 - \frac{1}{A} \sum_{i=1}^{n} \gamma_i \right). \]  

Eqn. (26) gives the ultrasonic through-thickness attenuation of a specimen based on the scattering cross section \( \gamma_i \) of the \( i \)-th void. Fig. 5 shows \( \alpha l \) versus the term \( 1 - \frac{1}{A} \sum_{i=1}^{n} \gamma_i \) based on eqn. (26). As indicated earlier, if the excitation frequency corresponds to a very long wavelength such that eqn. (11) is satisfied, the scattering cross section of each void can be evaluated from eqn. (1) for a spherical void having the same volume as the arbitrarily shaped void.

For the special case when the medium contains \( n \) identical voids, eqn. (26) can be simplified to
\[ \alpha = -\frac{1}{2l} \ln \left( 1 - \frac{n\gamma}{A} \right) \]  

where \( \gamma \) is the scattering cross section of a single void. For a specimen containing a void volume fraction \( V_v \), the total volume of voids encamassed by the volume of the input-output ultrasonic beam is
\[ nV = V_v A \]  

where \( V \) is the volume of a single void. Eqn. (28) can be rearranged to give the number of voids in the ultrasonic input-output beam as
\[ n = V_v \frac{A \lambda}{V} \]  

Substituting eqn. (29) into eqn. (27) gives
\[ \alpha = -\frac{1}{2l} \ln \left( 1 - \frac{V_v \frac{A \lambda}{V}}{A} \right) \]
Eqn. (30) gives the ultrasonic through-thickness attenuation $\alpha$ due to scattering by voids in terms of the void volume fraction for the special case when the medium contains randomly distributed identical voids. Fig. 5 shows $\alpha V$ versus the term $\left(1 - V_v \frac{\gamma_v}{V}\right)$ based on eqn. (30).

It is reemphasized that the attenuation expressed in eqns. (26) and (30) is due only to scattering by voids. The total attenuation of the medium containing the voids is

$$\alpha_T = \alpha_b + \alpha$$

where $\alpha_T$ is the total attenuation and $\alpha_b$ is the "base" attenuation; that is, the attenuation of the material when no voids are present.
CONCLUSIONS

Ultrasonic longitudinal wave through-thickness attenuation of a void-containing medium due to scattering has been considered. The attenuation was evaluated assuming no interaction between voids. The scattered power was assumed to be entirely lost, thus contributing to the ultrasonic attenuation.

The scattered power due to the presence of a void was described by the scattering cross section of the void. An exact solution exists for the scattering cross section of a spherical void and was given in eqn. (1). The scattering cross section of an ellipsoidal void was derived in accordance with the Born approximation and was given in eqn. (12). A further assumption, restricting the approximate solution to very long wavelengths as given in eqn. (11), was made.

The most striking result, although not totally unexpected, was that the exact shape of a void has negligible effect on its scattering cross section in the very long wavelength regime as expressed in eqn. (11). The scattering cross sections of spherical and ellipsoidal voids are proportional to the square of the volume of the void and proportional to the fourth power of the incident wave number. Thus, it is suggested that when very long wavelengths are considered, the exact solution of the scattering cross section of a spherical void of the same volume should be used for arbitrarily shaped voids.

The ultrasonic through-thickness attenuation was derived in terms of the scattering cross section of the individual voids encountered by the ultrasonic beam path and was given in eqn. (26). For the special case when a medium contains identical voids, the attenuation was derived in terms of the void volume fraction and the scattering cross section as given in eqn. (30).

This study demonstrates the scattering effects of voids for waves of very long wavelengths satisfying eqn. (11). The results provide an analytical basis for the simple modelling of voids in attenuation measurements; that is, model arbitrarily shaped voids as spherical voids of the same volume.

Experimental verification of the results are encouraged. Also, it is observed that, as implemented here, the Born approximation is of somewhat marginal utility in evaluating scattering cross sections of voids. Thus, a different approximation procedure [14] may be employed to better estimate scattering cross sections, especially for shorter wavelengths as expressed by eqn. (6).
REFERENCES


-13-


Fig. 1 Scattering cross section of a spherical void for incident longitudinal waves versus ratio of shear to longitudinal wave numbers.
Fig. 2 Schematic of scattering of ultrasonic plane longitudinal wave by an ellipsoidal void.
Fig. 3 Ratio of scattering cross section of an ellipsoidal void based on the Born approximation reduced to a spherical void to that of the exact solution versus the ratio of shear to longitudinal wave numbers $c$ for $k_p a_o << 1$. 

RATIO OF SCATTERING CROSS SECTION OF SPHERICAL VOID CALCULATED USING THE BORN APPROXIMATION TO THAT OF EXACT SOLUTION 

RATIO OF SHEAR TO LONGITUINAL WAVE NUMBERS ($c$)
ULTRASONIC BEAM HAVING PLANAR EXCITATION PRESSURE $p_o$

AREA $A$

INPUT ULTRASONIC EXCITATION PRESSURE $p_o$

SPECIMEN

THICKNESS $l$

OUTPUT TRANSMITTED PRESSURE $p_o e^{-\alpha l}$

Fig. 4 Schematic illustrating ultrasonic through-thickness testing of a specimen containing voids, $n$ of which are in the ultrasonic input-output beam path.
Fig. 5 Attenuation $\alpha$ of a specimen of thickness $l$ due to scattering by voids versus $(1 - \frac{1}{A} \sum_{i=1}^{n} \gamma_i)$ or $(1 - V_v \frac{\gamma l}{V})$ for the special case when the medium with void volume fraction $V_v$ contains many identical voids in the beam path, each with scattering cross section $\gamma$ and volume $V$. 
Ultrasonic longitudinal through-thickness attenuation in an isotropic medium due to scattering by randomly distributed voids is considered analytically. The attenuation is evaluated on the assumption of no interaction between voids. The scattered power is assumed to be entirely lost, thus accounting for the ultrasonic attenuation. The scattered power due to the presence of a void is described in terms of the scattering cross section of the void. An exact solution exists for the scattering cross section of a spherical void. An approximate solution for the scattering cross section of an ellipsoidal void is developed based on the so-called Born approximation commonly used in quantum mechanics. This approximate solution is valid for \( k_p a \ll 1 \), where \( k_p \) is the wave number of the incident longitudinal wave and \( a \) is the largest dimension of the void. It is found that the shape of the void has negligible effect on the scattering cross section and that only the volume of the void is important. Thus, it is noted that in cases where \( k_p a_1 \ll 1 \), the exact scattering cross section of a spherical void having the same volume as an arbitrarily shaped void can be used for evaluating ultrasonic attenuation. This study provides an analytical basis for such a simple substituional rule.